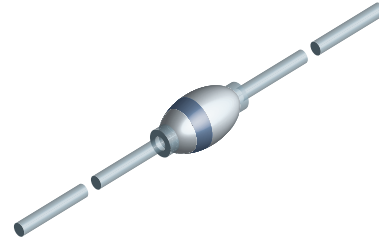


Standard Sinterglass Diode

Features

- High temperature metallurgically bonded constructed rectifiers
- Cavity-free glass passivated junction
- Hermetically sealed package
- 2.0 ampere operation at $T_{amb}=75\text{ }^{\circ}\text{C}$ with no thermal runaway



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Mechanical Data

Case: Sintered glass case, DO-204AP

Terminals: Solder plated axial leads, solderable per MIL-STD-750, Method 2026

Mounting Position: Any

Weight: 560 mg

Polarity: Color band denotes cathode end

Parts Table

Part	Type differentiation	Package
G2A	$V_{RRM} = 50\text{ V}$	DO-204AP (G1)
G2B	$V_{RRM} = 100\text{ V}$	DO-204AP (G1)
G2D	$V_{RRM} = 200\text{ V}$	DO-204AP (G1)
G2G	$V_{RRM} = 400\text{ V}$	DO-204AP (G1)
G2J	$V_{RRM} = 600\text{ V}$	DO-204AP (G1)
G2K	$V_{RRM} = 800\text{ V}$	DO-204AP (G1)
G2M	$V_{RRM} = 1000\text{ V}$	DO-204AP (G1)

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage = Repetitive peak reverse voltage	see electrical characteristics	G2A	$V_R = V_{RRM}$	50	V
	see electrical characteristics	G2B	$V_R = V_{RRM}$	100	V
	see electrical characteristics	G2D	$V_R = V_{RRM}$	200	V
	see electrical characteristics	G2G	$V_R = V_{RRM}$	400	V
	see electrical characteristics	G2J	$V_R = V_{RRM}$	600	V
	see electrical characteristics	G2K	$V_R = V_{RRM}$	800	V
	see electrical characteristics	G2M	$V_R = V_{RRM}$	1000	V
Maximum average forward rectified current	0.375 " (9.5 mm) lead length at $T_{amb} = 75\text{ }^{\circ}\text{C}$		$I_{F(AV)}$	2.0	A
Peak forward surge current	8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I_{FSM}	50	A
Maximum full load reverse current	full cycle average 0.375 " (9.5 mm) lead length at $T_{amb} = 100\text{ }^{\circ}\text{C}$		$I_{R(AV)}$	100	μA
Operating junction and storage temperature range			T_J, T_{STG}	-55 to +175	$^{\circ}\text{C}$

Maximum Thermal Resistance

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Typical thermal resistance ¹⁾	$R_{\theta JA}$	55	K/W

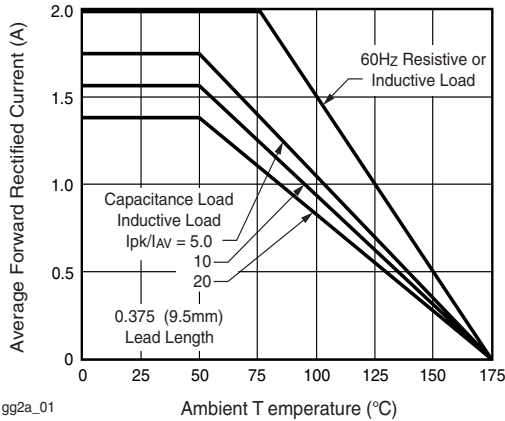
¹⁾ Thermal resistance from junction to ambient at 0.375 " (9.5 mm) lead length, P.C.B. mounted

Electrical Characteristics

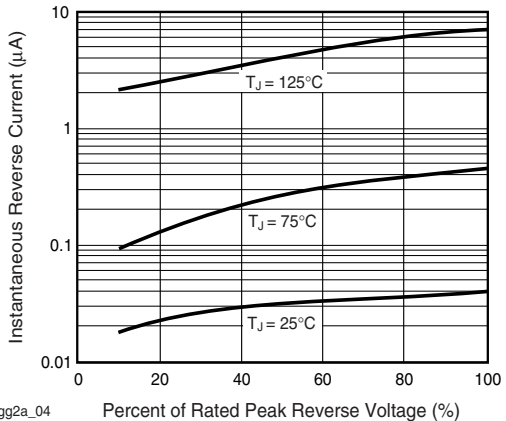
$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Part	Symbol	Typ.	Max	Unit
Maximum instantaneous forward voltage	$I_F = 2\text{ A}$	G2A	V_F		1.2	V
	$I_F = 2\text{ A}$	G2B	V_F		1.2	V
	$I_F = 2\text{ A}$	G2D	V_F		1.1	V
	$I_F = 2\text{ A}$	G2G	V_F		1.1	V
	$I_F = 2\text{ A}$	G2J	V_F		1.1	V
	$I_F = 2\text{ A}$	G2K	V_F		1.1	V
	$I_F = 2\text{ A}$	G2M	V_F		1.1	V
Maximum reverse current	$V_R = V_{RRM}, T_{amb} = 25\text{ }^{\circ}\text{C}$		I_R		1.0	μA
	$V_R = V_{RRM}, T_{amb} = 150\text{ }^{\circ}\text{C}$		I_R		100	μA
Typical reverse recovery time	$I_F = 0.5\text{ A}, I_R = 1.0\text{ A}, I_{rr} = 0.25\text{ A}$		t_{rr}	1.5		μs
Typical junction capacitance	$V_R = 4.0\text{ V}, f = 1\text{ MHz}$		C_J	15		pF

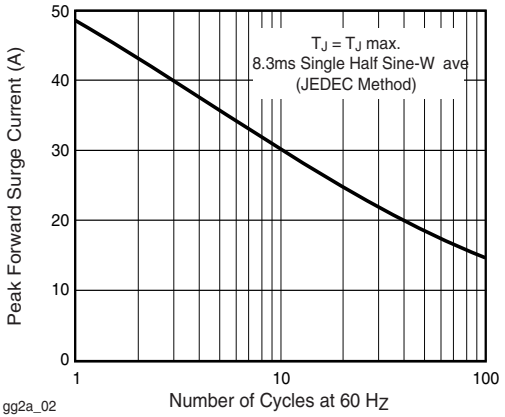
Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)



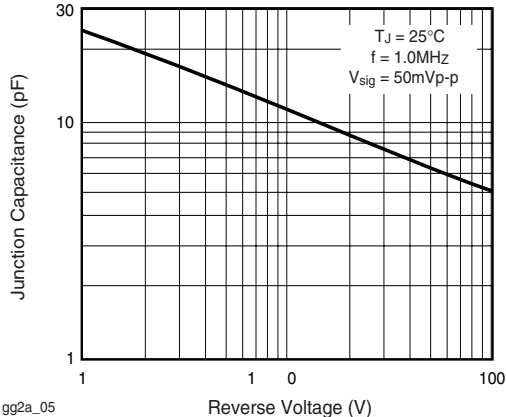
gg2a_01
Figure 1. Forward Current Derating Curve



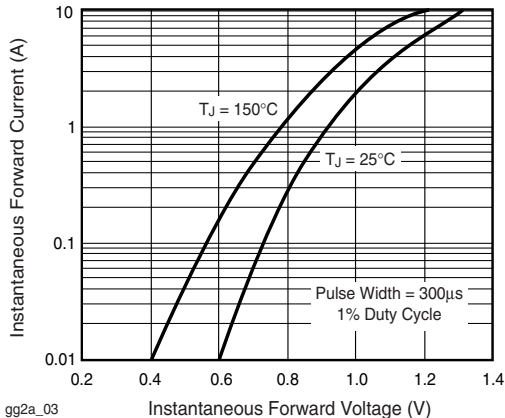
gg2a_04
Figure 4. Typical Reverse Characteristics



gg2a_02
Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

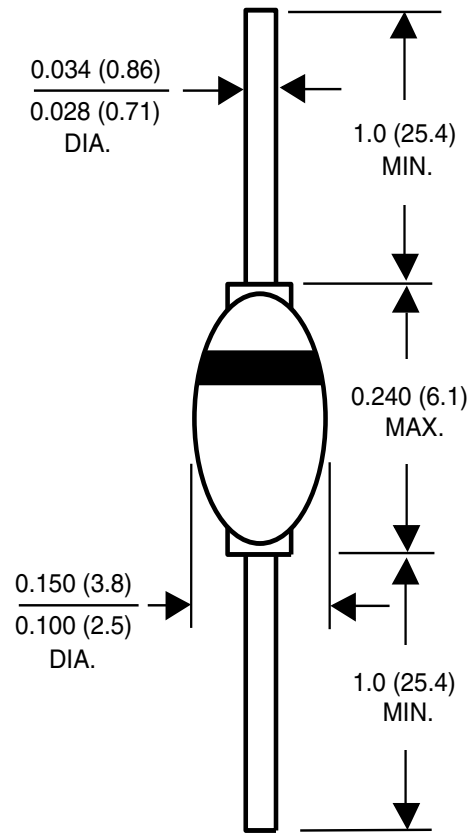


gg2a_05
Figure 5. Typical Junction Capacitance



gg2a_03
Figure 3. Typical Instantaneous Forward Characteristics

Package Dimensions in Inches (mm)



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Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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